

[Product Information]

Ver.1.0

IMX464LQR

Diagonal 9.04 mm (Type 1/1.8) CMOS Solid-state Image Sensor with Square Pixel for Color Cameras

Description

The IMX464LQR is a diagonal 9.04 mm (Type 1/1.8) CMOS active pixel type solid-state image sensor with a square pixel array and 4.17 M effective pixels. This chip operates with analog 2.9 V, digital 1.2 V, and interface 1.8 V triple power supply, and has low power consumption. High sensitivity, low dark current and no smear are achieved through the adoption of R, G and B primary color mosaic filters. This chip features an electronic shutter with variable charge-integration time.

(Applications: Surveillance cameras, FA cameras, Industrial cameras)

Features

- ◆ CMOS active pixel type dots
- ◆ Built-in timing adjustment circuit, H/V driver and serial communication circuit
- ◆ Input frequency: 6 to 27 MHz / 37.125 MHz / 74.25 MHz
- ◆ Number of recommended recording pixels: 2688 (H) × 1520 (V) approx. 4.09 M pixels
- ◆ Readout mode
 - All-pixel scan mode
 - Window cropping mode
 - Vertical / Horizontal direction-normal / inverted readout mode
- ◆ Readout rate
 - Maximum frame rate in All-pixel scan mode 2688 (H) × 1520 (V) A/D 10-bit : 90 frame/s
- ◆ High dynamic range (HDR) function
 - Multiple exposure HDR
 - Digital overlap HDR
- ◆ Variable-speed shutter function (resolution 1H units)
- ◆ 10-bit / 12-bit A/D converter
- ◆ CDS / PGA function
 - 0 dB to 29.4 dB : Analog Gain 29.4 dB (step pitch 0.3 dB)
 - 29.7 dB to 71.4 dB : Analog Gain 29.4 dB + Digital Gain 0.3 to 42 dB (step pitch 0.3 dB)
- ◆ Supports I/O
 - CSI-2 serial data output (2 Lane / 4 Lane, RAW10 / RAW12 output)
- ◆ Recommended exit pupil distance: -30 mm to $-\infty$

STARVIS

* STARVIS is a trademark of Sony Corporation. The STARVIS is back-illuminated pixel technology used in CMOS image sensors for surveillance camera applications. It features a sensitivity of 2000 mV or more per $1 \mu\text{m}^2$ (color product, when imaging with a 706 cd/m^2 light source, F5.6 in 1 s accumulation equivalent), and realizes high picture quality in the visible-light and near infrared light regions.

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Device Structure

- ◆ CMOS image sensor
- ◆ Image size Type 1/1.8
- ◆ Total number of pixels 2781 (H) × 1632 (V) approx. 4.53 M pixels
- ◆ Number of effective pixels 2712 (H) × 1538 (V) approx. 4.17 M pixels
- ◆ Number of active pixels 2712 (H) × 1536 (V) approx. 4.17 M pixels
- ◆ Number of recommended recording pixels 2688 (H) × 1520 (V) approx. 4.09 M pixels
- ◆ Unit cell size 2.9 μm (H) × 2.9 μm (V)
- ◆ Optical black Horizontal (H) direction: Front 0 pixel, rear 0 pixel
Vertical (V) direction: Front 13 pixels, rear 0 pixel
- ◆ Dummy Horizontal (H) direction: Front 0 pixel, rear 0 pixel
Vertical (V) direction: Front 0 pixel, rear 0 pixel
- ◆ Package 132 pin LGA

Image Sensor Characteristics

(Tj = 60 °C)

Item		Value	Remarks
Sensitivity (F5.6)	Typ.	TBD Digit	1/30 s accumulation 12 bit converted value
Saturation signal	Min.	TBD Digit	12 bit converted value

Basic Drive Mode

Drive mode	Recommended number of recording pixels	Maximum frame rate [frame/s]	Output interface	ADC [bit]
All pixel	2688 (H) × 1520 (V) approx. 4.09 M pixels	90	CSI-2	10